NSN 5961-00-665-3165

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-665-3165 **Inclosure Material:** Metal **Overall Length:** Between 1.177 inches and 1.197 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 regulator voltage **Current Rating Per Characteristic:** 500.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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